

TECHNICAL DATA
DATA SHEET 5364, REV. -

HERMETIC FAST RECOVERY RECTIFIER HIGH VOLTAGE

Features:

- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- Very High Surge Capacity
- Very suitable for medium to high frequency applications (upto 40 kHz)
- Soft Reverse Recovery at Low and High Temperature
- Trr guaranteed lower than 0.5μsec
- For ceramic seals use part number prefix SHDC
- Different Lead-bend options available
- Electrically / Mechanically Stable during and after Packaging

Maximum Ratings:

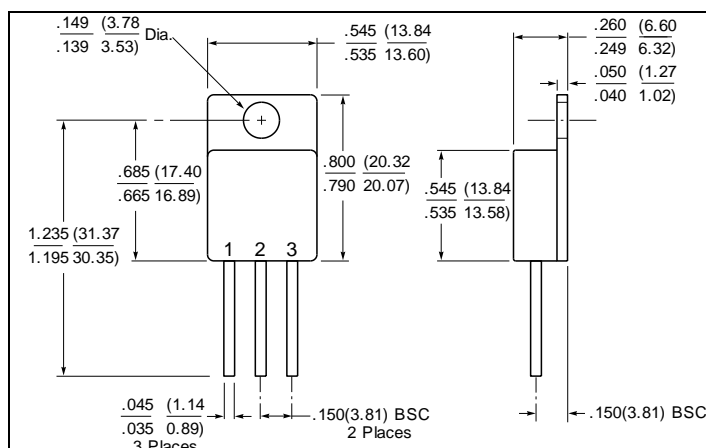
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	1200	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form, $T_C = 65^\circ\text{C}$	32	A
Max. Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3 msec, sine pulse, per leg	300	A
Thermal Resistance per leg	Z_{TH}	$T_C = 25^\circ\text{C}$	1.40	$^\circ\text{C} / \text{W}$
Max. Junction Temperature	T_J	-	- 55 to + 150	$^\circ\text{C}$
Max. Storage Temperature	T_{stg}	-	- 55 to + 150	$^\circ\text{C}$

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 9A, Pulse, $T_J = 25^\circ\text{C}$	1.15	1.25	V
		@ 32A, Pulse, $T_J = 25^\circ\text{C}$	1.75	1.85	
	V_{F2}	@ 9A, Pulse, $T_J = 125^\circ\text{C}$	-	1.18	V
		@ 32A, Pulse, $T_J = 125^\circ\text{C}$	-	1.75	
Max. Reverse Current	I_{R1}	@ $V_R = 1200\text{V}$, Pulse, $T_J = 25^\circ\text{C}$	2	50	μA
	I_{R2}	@ $V_R = 1200\text{V}$, Pulse, $T_J = 125^\circ\text{C}$	-	500	μA
Reverse Recovery Time	T_{RR}	$I_F = 0.5\text{A}$; $I_{RM} = 1\text{A}$, $I_{RR} = 0.25\text{A}$ $T_J = 25^\circ\text{C}$	0.3	0.5	μs
Capacitance	C_J	$V_R = 5\text{V}$, $f = 1\text{MHz}$, $V_{SIG} = 1\text{V}$	-	150	pF

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MECHANICAL DIMENSIONS: In Inches / mm



TO-254

PINOUTS

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	ANODE/CATHODE	CATHODE

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